





N-CHANNEL ENHANCEMENT MODE MOSFET

Features

- Low On-Resistance
- Very Low Gate Threshold Voltage
- Low Input Capacitance
- ESD Protected Gate to 2kV
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q101 Standards for High Reliability
- PPAP Capable (Note 4)

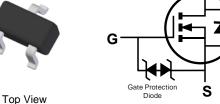
Mechanical Data

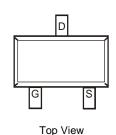
- Case: SOT523
- Case Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Matte Tin Finish Annealed over Alloy 42 Leadframe. Solderable per MIL-STD-202, Method 208 (3)
- Terminal Connections: See Diagram
- Weight: 0.002 grams (Approximate)

SOT523









May 2019

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Equivalent Circuit

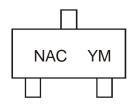
Ordering Information (Note 5)

Part Number	Qualification	Case	Packaging		
DMN55D0UT-7	Commercial	SOT523	3,000/Tape & Reel		
DMN55D0UTQ-7	Automotive	SOT523	3.000/Tape & Reel		

Notes:

- 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant.
- 2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + CI) and <1000ppm antimony compounds.
- 4. Automotive products are AEC-Q101 qualified and are PPAP capable. Automotive, AEC-Q101 and standard products are electrically and thermally the same, except where specified. For more information, please refer to https://www.diodes.com/quality/.
- 5. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/

Marking Information



NAC = Product Type Marking Code YM = Date Code Marking Y = Year (ex: G = 2019)M = Month (ex: 9 = September)

Date Code Key

Year	2007		2015	2016	201	7 20)18	2019	2020	2021	2022	2023
Code	U		С	D	Е		F	G	Н	I	J	K
Month	Jan	Feb	Mar	Apr	May	Jun	Jul	Aug	Sep	Oct	Nov	Dec
Code	1	2	3	4	5	6	7	8	9	0	N	D



Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Drain-Source Voltage	V_{DSS}	50	V
Gate-Source Voltage	V_{GSS}	±12	V
Drain Current (Note 6) Continuous	I _D	160	mA
Pulsed Drain Current (Note 6)	I _{DM}	560	mA

Thermal Characteristics

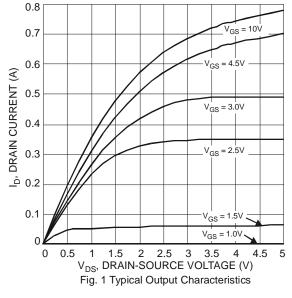
Characteristic	Symbol	Value	Unit
Total Power Dissipation (Note 6)	P_{D}	200	mW
Thermal Resistance, Junction to Ambient	R _{0JA}	625	°C/W
Operating and Storage Temperature Range	T _J , T _{STG}	-55 to +150	°C

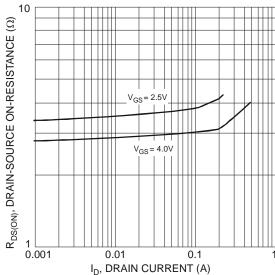
Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

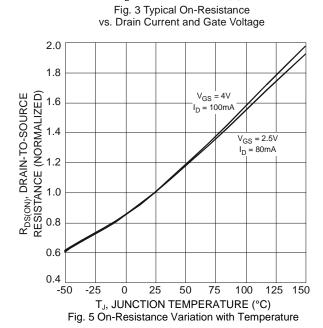
Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition		
OFF CHARACTERISTICS (Note 7)								
Drain-Source Breakdown Voltage	BV_{DSS}	50			>	$V_{GS} = 0V, I_D = 250\mu A$		
Zero Gate Voltage Drain Current	I _{DSS}	1		1	μΑ	$V_{DS} = 50V$, $V_{GS} = 0V$		
Gate-Source Leakage	I _{GSS}	_	_	1.0	μA	$V_{GS} = \pm 8V$, $V_{DS} = 0V$		
· ·				5.0	P	$V_{GS} = \pm 12V$, $V_{DS} = 0V$		
ON CHARACTERISTICS (Note 7)	,			•				
Gate Threshold Voltage	V _{GS(TH)}	0.7	0.8	1.0	V	$V_{DS} = V_{GS}$, $I_D = 250\mu A$		
Static Drain-Source On-Resistance	D-s/s/	_	3.1	4	0	$V_{GS} = 4V, I_D = 100mA$		
Static Drain-Source On-Nesistance	R _{DS(ON)}	_	4	5	12	$V_{GS} = 2.5V, I_D = 80mA$		
Forward Transconductance	g _{FS}	180	_	_	mS	$V_{DS} = 10V$, $I_D = 100mA$, $f = 1.0kHz$		
Diode Forward Voltage	V_{SD}	_	0.70	1.3	V	$V_{GS} = 0V, I_{S} = 100mA$		
DYNAMIC CHARACTERISTICS (Note 8)	DYNAMIC CHARACTERISTICS (Note 8)							
Input Capacitance	Ciss	l	25		рF			
Output Capacitance		l	5		рF	$V_{DS} = 10V, V_{GS} = 0V, f = 1.0MHz$		
Reverse Transfer Capacitance	Crss	-	2.1		рF			
Gate Resistance	R _G	l	500	_	Ω	$f = 1MHz$, $V_{GS} = 0V$, $V_{DS} = 0V$		
Total Gate Charge (V _{GS} = 4V)	Q_{G}		295		рС			
Total Gate Charge (V _{GS} = 8V)	Q_{G}		636	_	рC	$V_{DS} = 10V$,		
Gate-Source Charge	Q_{GS}		72		рC	$I_D = 100 \text{mA}$		
Gate-Drain Charge	Q_{GD}	1	18	_	рС			
Turn-On Delay Time	t _{D(ON)}	l	6.0		ns			
Turn-On Rise Time		-	4.4	_	ns	$V_{DD} = 10V, V_{GS} = 4V,$		
Turn-Off Delay Time	t _{D(OFF)}	-	23.4	_	ns	$R_G = 25\Omega$, $I_D = 100$ mA		
Turn-Off Fall Time	t _F	l	11.0	_	ns			

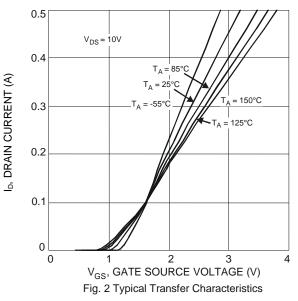
Device mounted on FR-4 PCB, with minimum recommended pad layout.
Short duration pulse test used to minimize self-heating effect.
Guaranteed by design. Not subject to product testing.











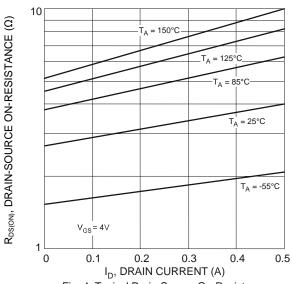
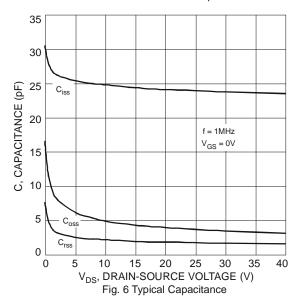


Fig. 4 Typical Drain-Source On-Resistance vs. Drain Current and Temperature





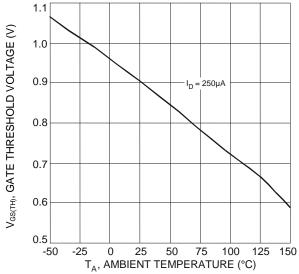
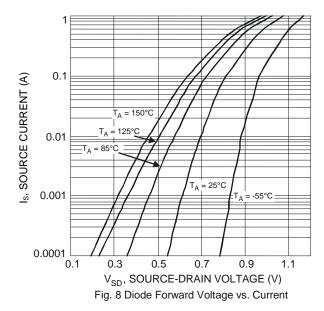
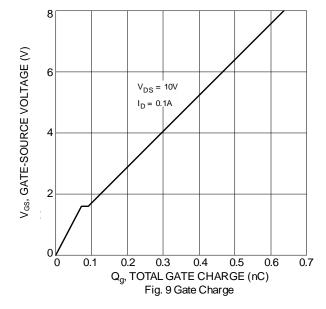


Fig. 7 Gate Threshold Variation vs. Ambient Temperature





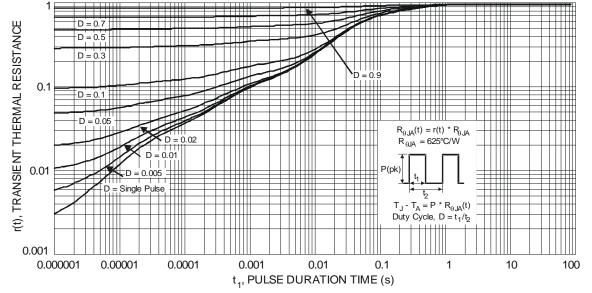


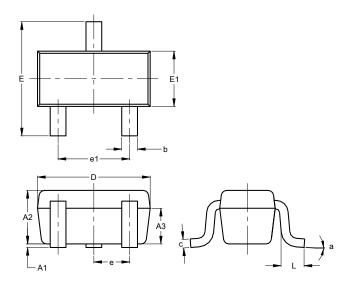
Fig. 10 Transient Thermal Response



Package Outline Dimensions

Please see http://www.diodes.com/package-outlines.html for the latest version.

SOT523

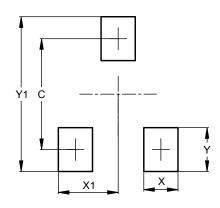


SOT523							
Dim	Min	Max	Тур				
A1	0.00	0.10	0.05				
A2	0.60	0.80	0.75				
A3	0.45	0.65	0.50				
b	0.15	0.30	0.22				
С	0.10	0.20	0.12				
D	1.50	1.70	1.60				
Е	1.45	1.75	1.60				
E1 0.75		0.85	0.80				
е	0.50 BSC						
e1	0.90	1.10	1.00				
L	0.20	0.40	0.33				
а	0°		8°				
Al	All Dimensions in mm						

Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.

SOT523



Dimensions	Value (in mm)		
С	1.29		
Х	0.40		
X1	0.70		
Y	0.51		
Y1	1.80		



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